

# Electron Dynamics: Transport and Ultrafast Processes

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Physics Department Seminar  
Oct 8, 2007



## Research Group:

Felipe Murphy-Armando (SiGe alloys)

Eamonn Murray (ultra-fast optical excitation)

Amanuel Teweldeberhan (vibrational probes of structure)

Ivana Bosa (GaAsN - photoluminescence)

Sian Joyce (SiGe alloys, NMR)

John Buckeridge (GaAsN heterostructures - theory)

Tassilo Dannecker (GaAsN heterostructures - expt.)

## Tyndall Collaborators:

Eoin O'Reilly

Andy Lindsay

Jim Greer

## Recent Group Members:

Henni Ouerdane

Dermot McPeake

Joe Stenuit (GaAsN alloys - structure, electr.)



# Selected Highlights:

1. Intervalley alloy scattering in SiGe
2. Interatomic Forces in a Photoexcited Solid

Phys. Rev. Lett. **97**, 096606 (2006)  
Science **315**, 633 (2007)



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# Alloy Scattering in SiGe

Felipe Murphy-Armando and Sian Joyce

Phys. Rev. Lett. **97**, 096606 (2006)

Phys. Rev. B **75**, 155201 (2007)



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# Ongoing Work - Charge Transport (SFI)

Area 1: General theory of scattering in disordered media

Area 2: ab initio calculation of alloy scattering in  $\text{Si}_{(1-x)}\text{Ge}_x$

Area 3: Tight-binding calculation of scattering in  $\text{GaAs}_{(1-x)}\text{N}_x$

General Goal: calculate bulk transport from first principles

$\text{Si}_{(1-x)}\text{Ge}_x$  :

- \* full alloy stability range ( $0 < x < 1$ )
- \* weak scattering
- \* “virtual crystal” good first approximation

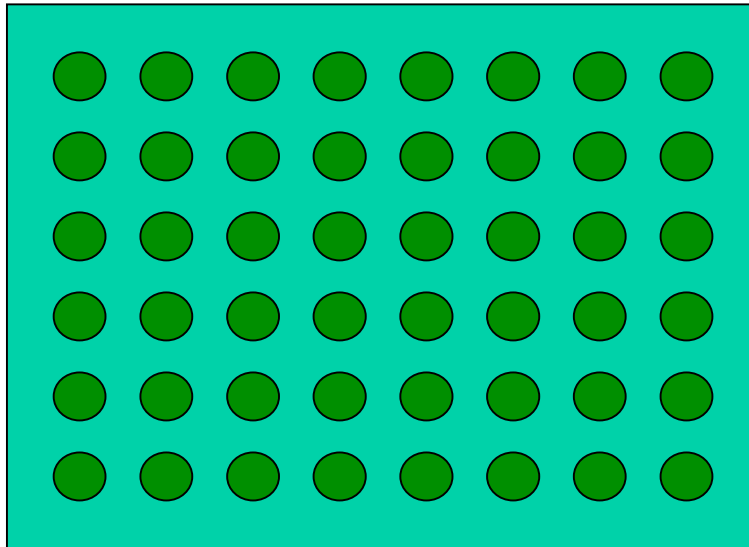
$\text{GaAs}_{(1-x)}\text{N}_x$  :

- \* limited alloy range (dilute nitride,  $x \sim 1\text{-}3\%$ )
- \* very strong N scattering
- \* virtual crystal approximation not useful



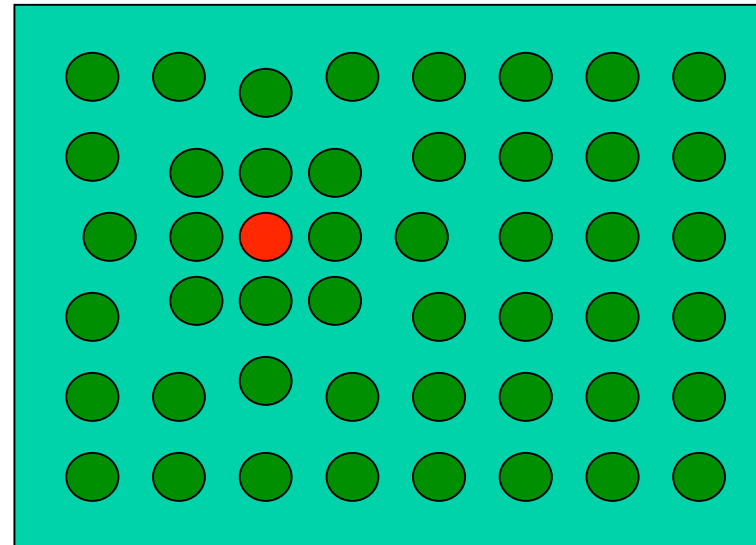
# Supercell Approach

Perfect lattice



Calculate energy  $E_0$  and  $\chi$

Lattice with defect  
(include lattice relaxation)

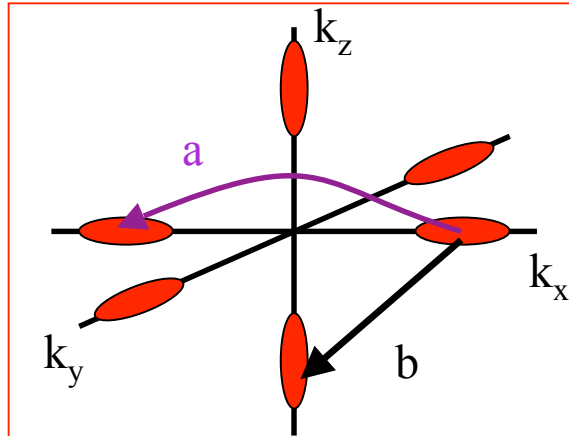


Calculate  $E_1$  and  $\chi$

$$\langle \chi | \hat{H} | \chi \rangle = (E_1 - E_0) \langle \chi | \chi \rangle$$

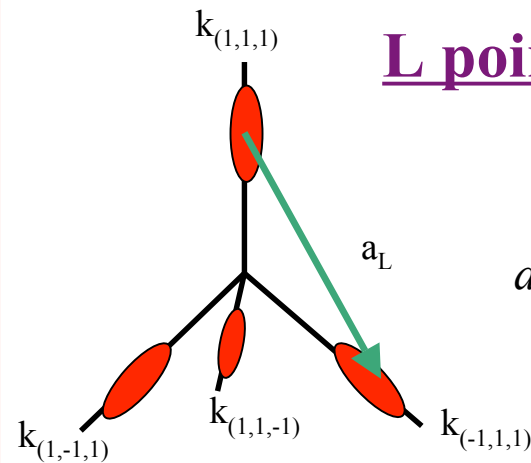


# Alloy Inter-valley scattering



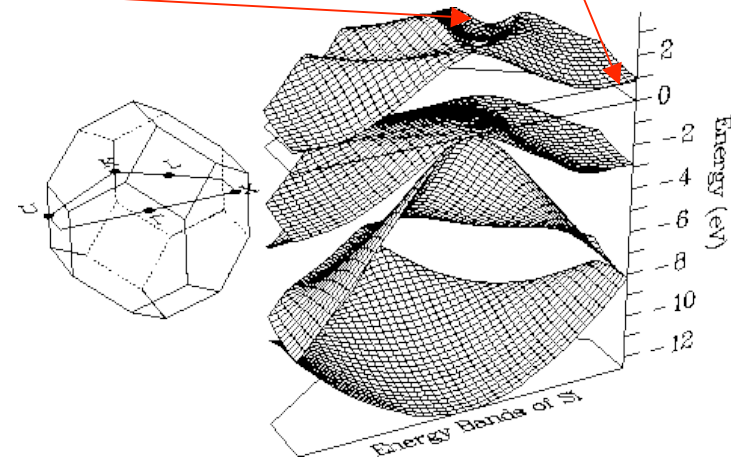
$\Gamma$  point

$$dH_{\Gamma} = \begin{array}{c} \begin{array}{cccccc} dE & da & db & db & db & db \\ da & dE & db & db & db & db \\ db & db & dE & da & db & db \\ db & db & da & dE & db & db \\ db & db & db & db & dE & da \\ db & db & db & db & da & dE \end{array} \end{array}$$

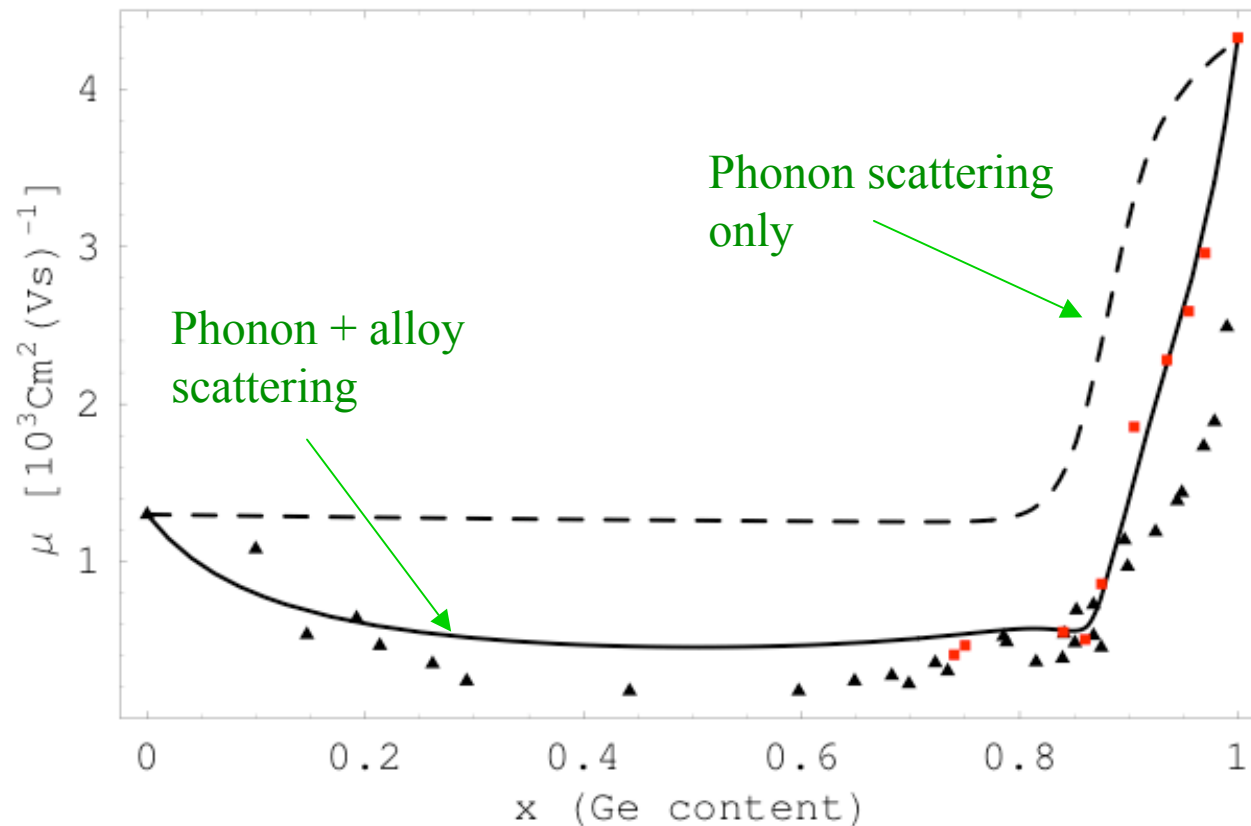


L point

$$dH_L = \begin{array}{c} \begin{array}{cccc} dE & da & da & da \\ da & dE & da & da \\ da & da & dE & da \\ da & da & da & dE \end{array} \end{array}$$



# Results: Mobility from Alloy Scattering



Murphy-Armando  
PRL (2006)

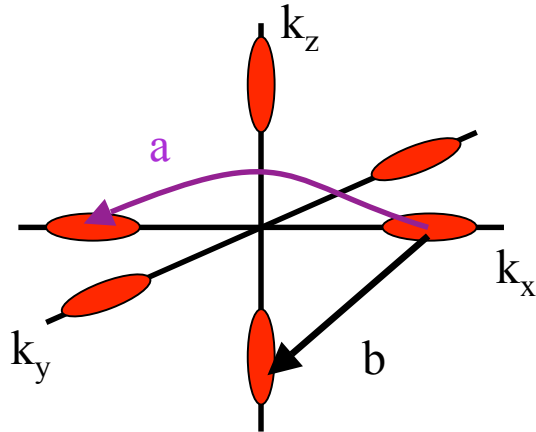
Expts:    ▲ G. Busch and O. Vogt, *Helv. Phys. Acta* 33, 437 (1960)  
            ■ M. Glicksman, *Phys. Rev.* 111, 125 (1958)



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# Summary: SiGe Alloys



Inter-valley alloy scattering parameters well-determined for the first time

## Future Applications:

1. Strained materials
2. III-V materials
3. Alloy scattering in SiGe nanoscale structures
4. Electron-phonon coupling in confined structures



# Ultra-fast Carrier and Phonon Dynamics

Eamonn Murray

Goal: Understand energy relaxation processes in photo-excited materials

Phys. Rev. Lett. **93**, 109701 (2004)  
Phys. Rev. B **72**, 060301(R) (2005)  
Science **315**, 633 (2007)  
Phys. Rev. B **75**, 184301 (2007)



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# Collaborators

## Theory:

Paul Tangney (Imperial College)

Eamonn Murray

David Prendergast (Berkeley, LBL)

Tadashi Ogitsu (Livermore)

## Experiments:

David Reis (Michigan)

David Fritz (Michigan)

Jared Wahlstrand (Michigan)

Phil Bucksbaum (Stanford)

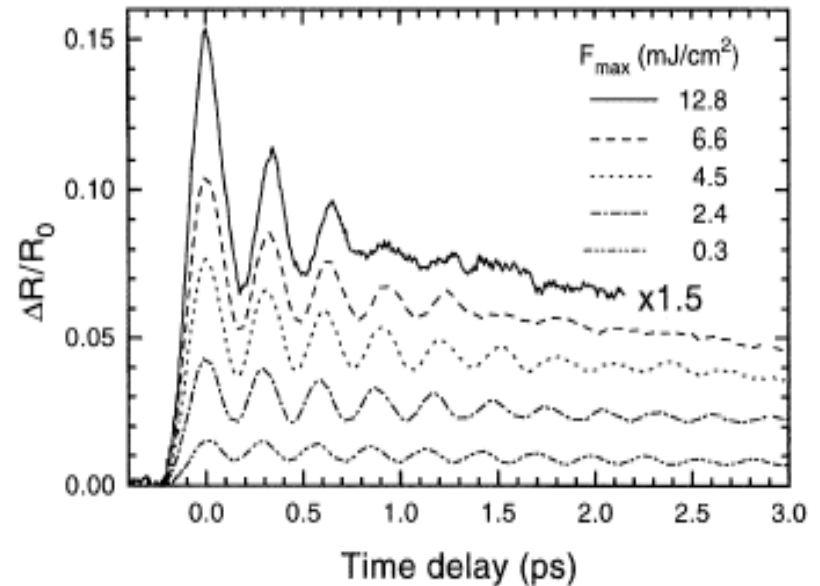
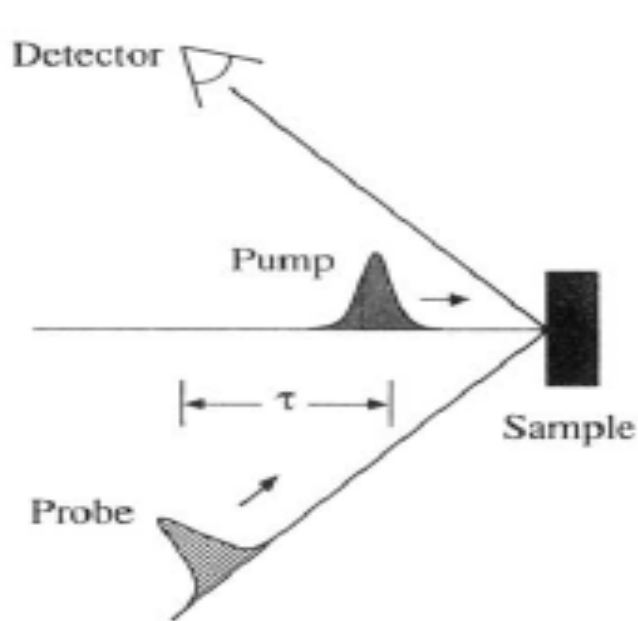
Roberto Merlin (Michigan)

SPPS (Stanford, SLAC)

FOCUS Center, Michigan



# Pump-Probe Experiments



Expt. on Te - Hunsche et al. (1995)

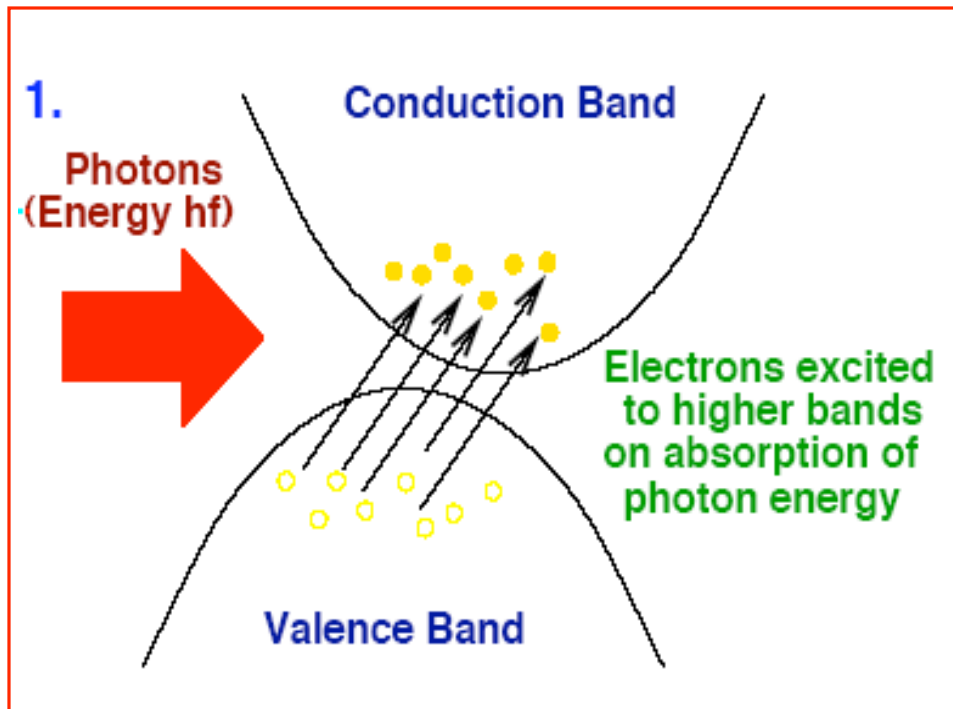
- Changes in reflected probe pulse energy versus time delay between the pump and probe pulses
- Plasma and ionic motion alter reflectivity



# Displacive Photoexcitation Process

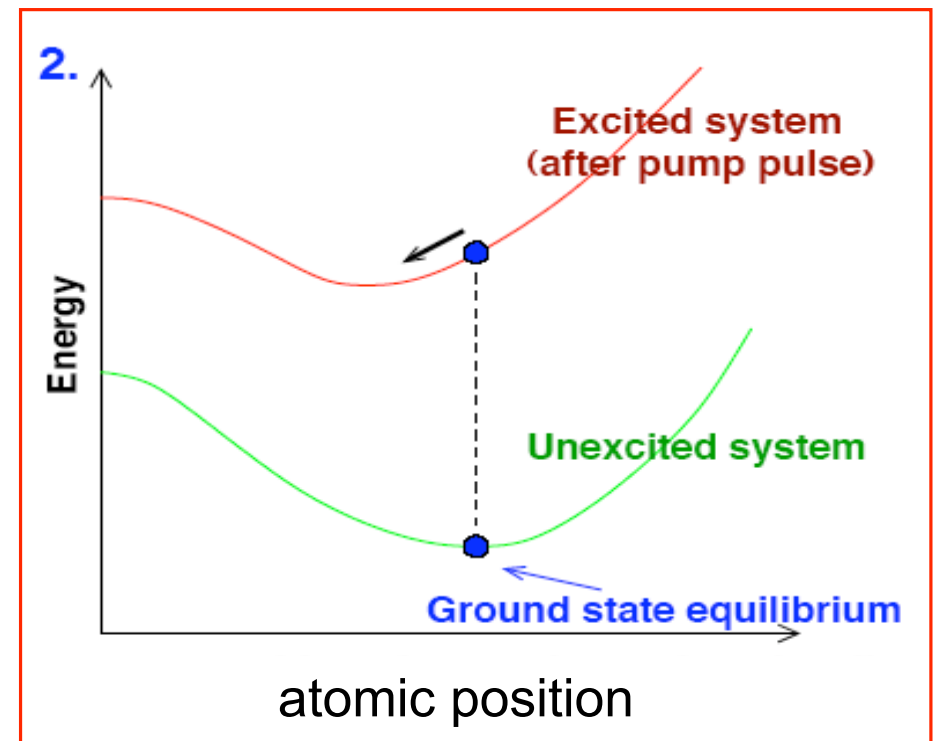
## Creation of Electron-hole Plasma

Timescale: < 100 fs

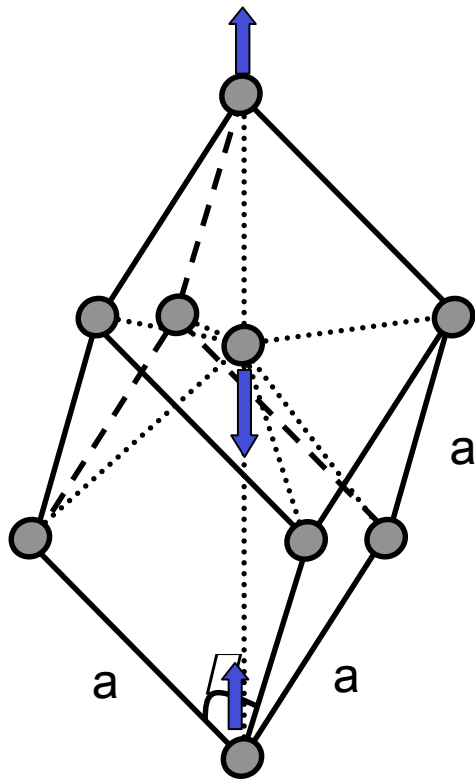


Note: does NOT include any coherent electronic polarization effects!

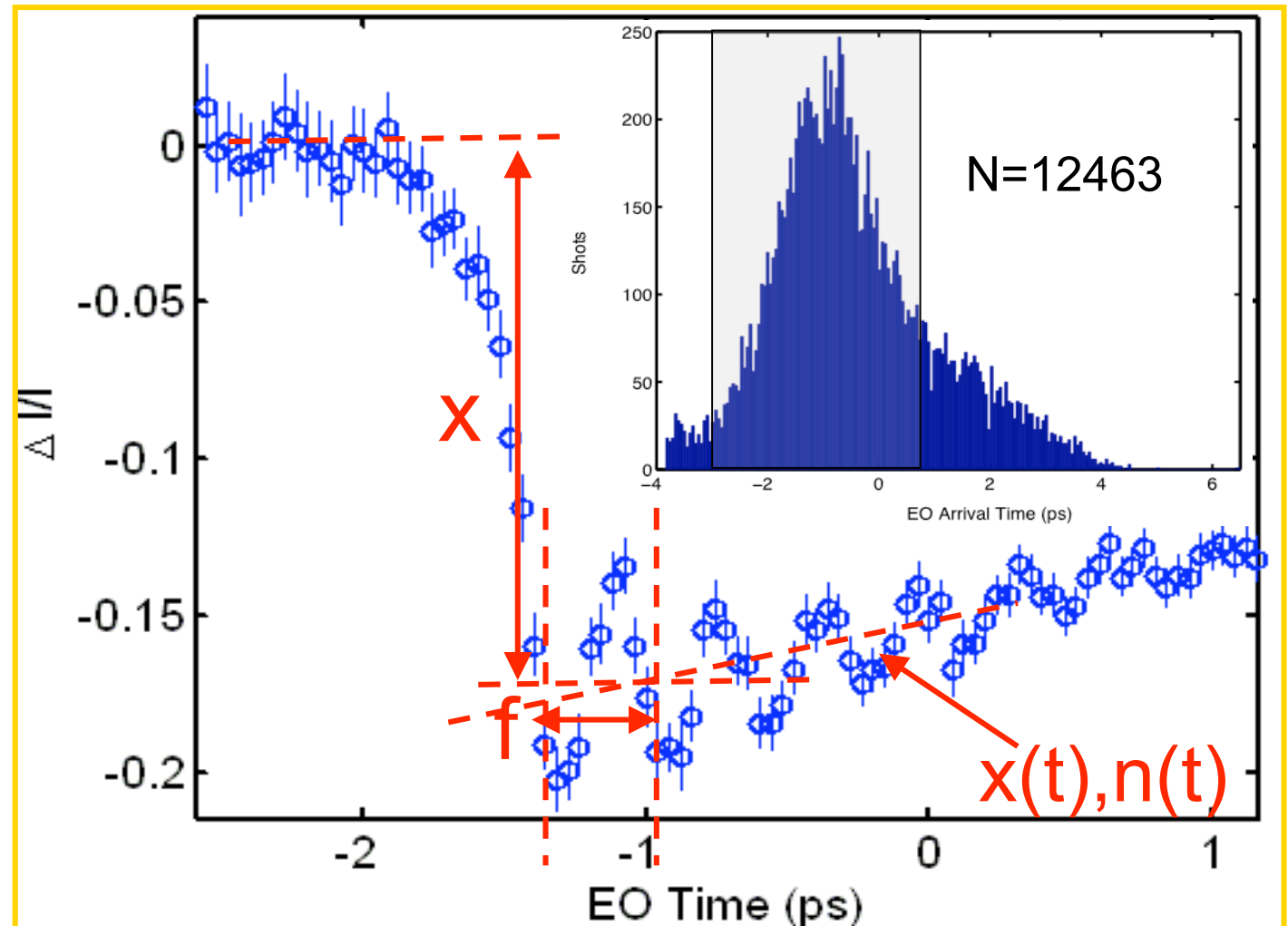
## Altered Atomic Equilibrium



# SPPS x-ray measurement of Bi dynamics



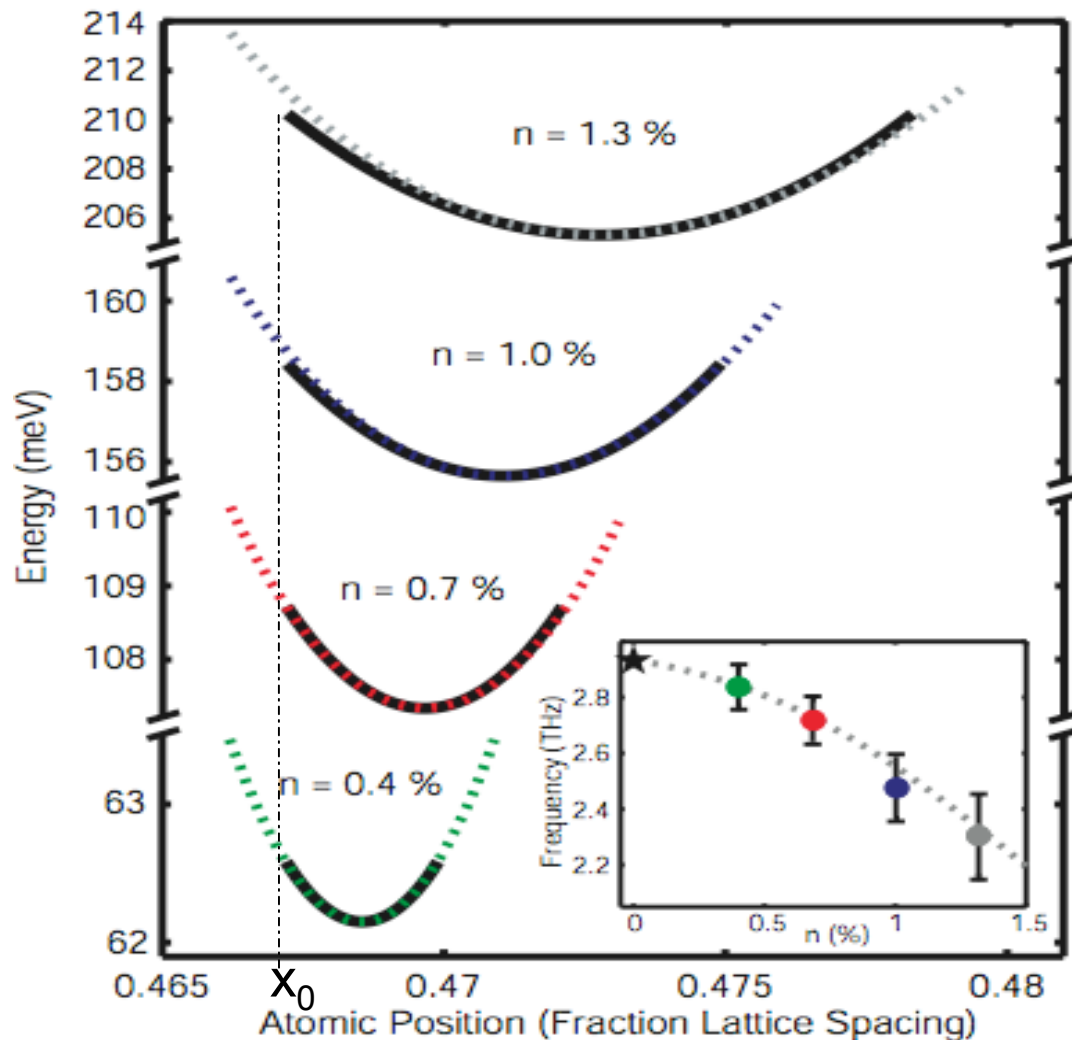
Fritz et al. (2007)



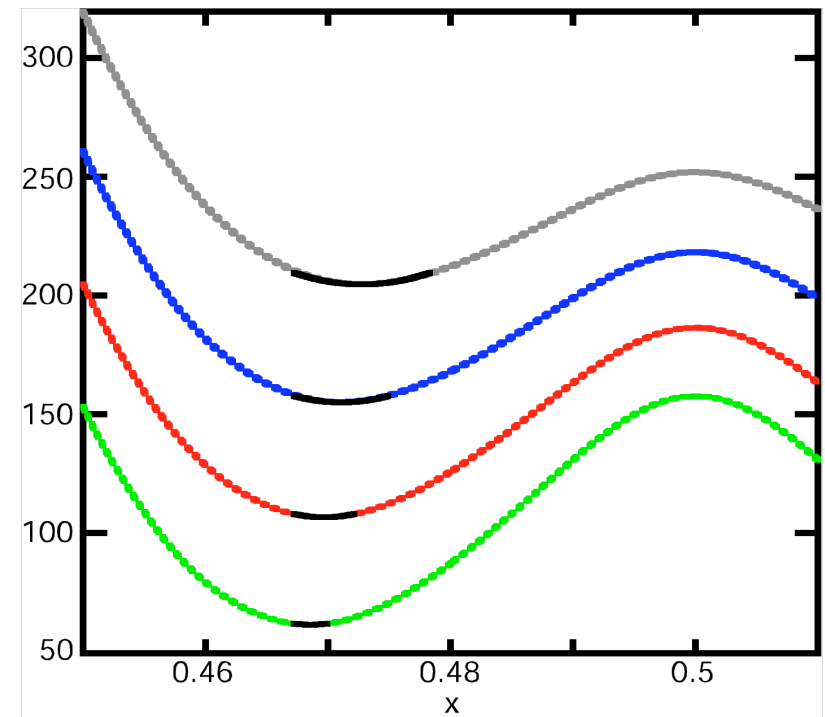
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# Measured Interatomic Potential of Bi



## Calculated energy curves



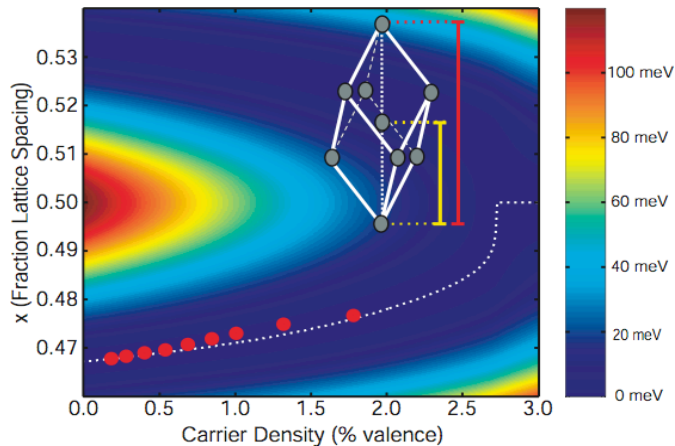
Fritz et al. *Science* (2007)



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# Summary: Ultrafast Dynamics



First time Interatomic Forces have been Calculated and Measured for a photo-excited material

## Future Applications:

1. Energy dissipation and phonon “bottlenecks”
2. Phonon probe of carrier inter-band relaxation
3. InSb phonon dynamics

**4th year project!!**

